

LF253 LF353

Wide bandwidth dual JFET operational amplifiers

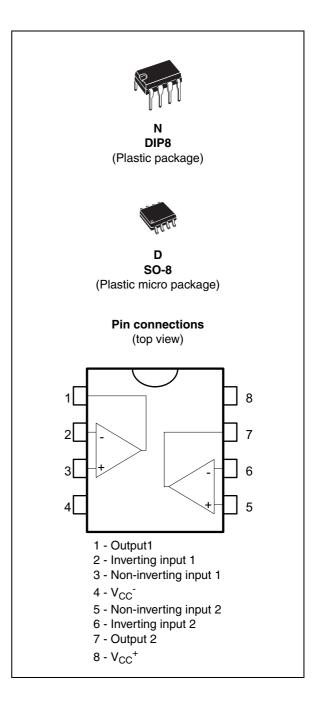
Features

- Low power consumption
- Wide common-mode (up to V_{CC}⁺) and differential voltage range
- Low input bias and offset current
- Output short-circuit protection
- High input impedance JFET input stage
- Internal frequency compensation
- Latch up free operation
- High slew rate 16 V/µs (typical)

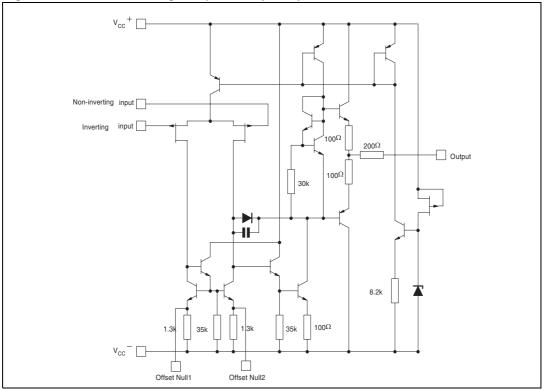
Description

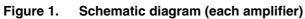
These circuits are high speed JFET input dual operational amplifiers incorporating well matched, high voltage JFET and bipolar transistors in a monolithic integrated circuit.

The devices feature high slew rates, low input bias and offset currents, and low offset voltage temperature coefficient.



1 Schematics







2 Absolute maximum ratings and operating conditions

Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage ⁽¹⁾	±18	V
Vi	Input voltage ⁽²⁾	±15	V
V _{id}	Differential input voltage ⁽³⁾	±30	V
R _{thja}	Thermal resistance junction to ambient ⁽⁴⁾ SO-8 DIP8	125 85	°C/W
R _{thjc}	Thermal resistance junction to case ⁽⁴⁾ SO-8 DIP8	40 41	°C/W
	Output short-circuit duration ⁽⁵⁾	Infinite	
T _{stg}	Storage temperature range	-65 to +150	°C
	HBM: human body model ⁽⁶⁾	1	kV
ESD	MM: machine model ⁽⁷⁾	200	V
	CDM: charged device model ⁽⁸⁾	1.5	kV

Table 1. Absolute maximum ratings

1. All voltage values, except differential voltage, are with respect to the zero reference level (ground) of the supply voltages where the zero reference level is the midpoint between V_{CC}^+ and V_{CC}^- .

2. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 volts, whichever is less.

- 3. Differential voltages are the non-inverting input terminal with respect to the inverting input terminal.
- 4. Short-circuits can cause excessive heating and destructive dissipation. Values are typical.
- 5. The output may be shorted to ground or to either supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded
- Human body model: a 100 pF capacitor is charged to the specified voltage, then discharged through a 1.5 kΩ resistor between two pins of the device. This is done for all couples of connected pin combinations while the other pins are floating.
- 7. Machine model: a 200 pF capacitor is charged to the specified voltage, then discharged directly between two pins of the device with no external series resistor (internal resistor < 5 Ω). This is done for all couples of connected pin combinations while the other pins are floating.
- 8. Charged device model: all pins and the package are charged together to the specified voltage and then discharged directly to the ground through only one pin. This is done for all pins.

Symbol	Parameter	LF253	LF353	Unit
V _{CC}	Supply voltage	6 to	36	V
T _{oper}	Operating free-air temperature range	-40 to +105	0 to +70	°C

Table 2. Operating conditions



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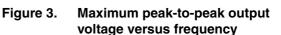
3 Electrical characteristics

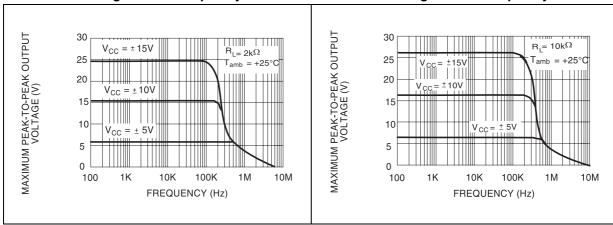
Table 3.Electrical characteristics at $V_{CC} = \pm 15 \text{ V}$, $T_{amb} = +25^{\circ}C$ (unless otherwise specified)

$ \begin{array}{ c c c c } V_{io} & Input offset voltage (R_{s} = 10k\Omega) \\ T_{min} \leq T_{amb} \leq T_{max} & 10 \\ \hline DV_{io} & Input offset voltage drift & 10 \\ \hline I_{io} & Input offset current (^{1)} & 5 \\ T_{min} \leq T_{amb} \leq T_{max} & 20 \\ \hline I_{ib} & Input bias current (^{1)} & 20 \\ T_{min} \leq T_{amb} \leq T_{max} & 25 \\ \hline A_{vd} & Large signal voltage gain (R_{L} = 2k\Omega V_{o} = \pm 10V) & 50 \\ T_{min} \leq T_{amb} \leq T_{max} & 25 \\ \hline SVR & Supply voltage rejection ratio (R_{S} = 10k\Omega) & 80 \\ T_{min} \leq T_{amb} \leq T_{max} & 80 \\ \hline I_{CC} & Supply current, no load \\ T_{min} \leq T_{amb} \leq T_{max} & 80 \\ \hline V_{icm} & Input common mode voltage range & \pm 11 \\ \hline +15 \\ -12 \\ \hline CMR & Common mode rejection ratio (R_{S} = 10k\Omega) & 70 \\ T_{min} \leq T_{amb} \leq T_{max} & 70 \\ \hline I_{OS} & Output short-circuit current \\ T_{min} \leq T_{amb} \leq T_{max} & 10 \\ \hline V_{copp} & R_{L} = 2k\Omega \\ R_{L} = 10k\Omega \\ T_{L} \leq L \leq L \\ \hline \end{array}$	10 13 100 4 200	mV µV/°C pA nA
$\begin{array}{ c c c c c } \hline Input offset voltage drift & 10 \\ \hline Input offset current (1) \\ \hline Ilio & Input offset current (1) \\ \hline T_{min} \leq T_{amb} \leq T_{max} & 20 \\ \hline Input bias current (1) \\ \hline T_{min} \leq T_{amb} \leq T_{max} & 25 \\ \hline A_{vd} & Large signal voltage gain (R_L = 2k\Omega, V_o = \pm 10V) & 50 & 200 \\ \hline T_{min} \leq T_{amb} \leq T_{max} & 25 \\ \hline SVR & Supply voltage rejection ratio (R_S = 10k\Omega) & 80 & 86 \\ \hline T_{min} \leq T_{amb} \leq T_{max} & 80 \\ \hline Icc & Supply current, no load \\ \hline T_{min} \leq T_{amb} \leq T_{max} & 80 \\ \hline V_{icm} & Input common mode voltage range & \pm 11 & \pm 15 \\ \hline -12 \\ \hline CMR & Common mode rejection ratio (R_S = 10k\Omega) & 70 & 86 \\ \hline T_{min} \leq T_{amb} \leq T_{max} & 70 \\ \hline Ios & Output short-circuit current \\ \hline T_{min} \leq T_{amb} \leq T_{max} & 10 \\ \hline V_{ios} & Output short-circuit current \\ \hline T_{min} \leq T_{amb} \leq T_{max} & 10 \\ \hline Ios & Output voltage swing \\ \hline R_L = 2k\Omega & R_L = 10k\Omega & 12 \\ \hline R_L = 10k\Omega & 12 \\ \hline 12 & 13.5 \\ \hline \end{array}$	100 4 200	μV/°C pA
$\begin{tabular}{ c c c c c } \hline I_{io} & Input offset current (1) & 5 & 5 & 5 \\ \hline T_{min} \leq T_{amb} \leq T_{max} & 20 & 20$	4 200	pА
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$\begin{array}{c c c c c c c c c c c c c c c c c c c $	200	nA
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$\frac{1}{1} \frac{1}{1} \frac{1}$		pА
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	20	nA
$\frac{1}{\min \leq 1} \frac{1}{\max} \leq 1}{\max} = 10 \text{ k}\Omega}$ $\frac{23}{1}$ $\frac{1}{1} \frac{1}{1} \frac{1}{1$		V/mV
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$I_{CC} = \begin{cases} Supply current, no load \\ T_{min} \leq T_{amb} \leq T_{max} \end{cases} $ $I = 1.4$ $V_{icm} = I_{nput} common mode voltage range $ $I_{1.4} = 1.4$ $V_{icm} = I_{nput} common mode voltage range $ $I_{1.4} = 1.4$ $I_{1.4} = 1.$		dB
$\begin{array}{c cc} I_{CC} & T_{min} \leq T_{amb} \leq T_{max} \\ \hline \\ V_{icm} & Input common mode voltage range \\ \hline \\ CMR & Common mode rejection ratio (R_{S} = 10k\Omega) \\ T_{min} \leq T_{amb} \leq T_{max} \\ \hline \\ I_{OS} & Output short-circuit current \\ T_{min} \leq T_{amb} \leq T_{max} \\ \hline \\ Output voltage swing \\ R_{L} = 2k\Omega \\ R_{L} = 10k\Omega \\ \hline \end{array} \begin{array}{c} 10 \\ 12 \\ 13.5 \end{array}$		
$ \begin{array}{c c} V_{icm} & \text{Input common mode voltage range} & \pm 11 & \pm 15 \\ -12 \\ \hline V_{icm} & \text{Common mode rejection ratio } (R_S = 10 \text{k}\Omega) & 70 & 86 \\ \hline T_{min} \leq T_{amb} \leq T_{max} & 70 & 70 \\ \hline I_{OS} & \text{Output short-circuit current} & 10 & 40 \\ \hline T_{min} \leq T_{amb} \leq T_{max} & 10 & 10 \\ \hline Output voltage swing & & & \\ R_L = 2 \text{k}\Omega & & 10 & 12 \\ R_L = 10 \text{k}\Omega & & 12 & 13.5 \\ \hline \end{array} $	3.2 3.2	mA
$ \begin{array}{c c} V_{icm} & \text{input common mode voltage range} & -12 \\ \hline \\ CMR & Common mode rejection ratio (R_S = 10k\Omega) & 70 \\ T_{min} \leq T_{amb} \leq T_{max} & 70 \\ \hline \\ I_{OS} & Output short-circuit current & 10 \\ T_{min} \leq T_{amb} \leq T_{max} & 10 \\ \hline \\ 0 & Utput voltage swing & R_L = 2k\Omega \\ R_L = 10k\Omega & 12 \\ 13.5 \end{array} $		
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$\begin{array}{c c} I_{OS} & T_{min} \leq T_{amb} \leq T_{max} \\ \hline \\ & Output voltage swing \\ & R_L = 2k\Omega \\ & R_L = 10k\Omega \\ \end{array} \qquad \qquad$		uВ
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	60	mA
$ \begin{array}{c} R_{L} = 2k\Omega & 10 \\ R_{L} = 10k\Omega & 12 \\ \end{array} $	60	
$R_{\rm L} = 10 k\Omega$ 12 13.5		
+V -		
$T_{min} \leq T_{amb} \leq T_{max}$		V
$R_L = 2k\Omega$ 10		
$R_{L} = 10k\Omega $		
SR Slew rate, $V_i = 10V$, $R_L = 2k\Omega$, $C_L = 100pF$, unity gain 12 16		V/µs
t _r Rise time, V _i = 20mV, R _L = 2k Ω , C _L = 100pF, unity gain 0.1		μs
K_{ov} Overshoot, $V_i = 20$ mV, $R_L = 2k\Omega$, $C_L = 100$ pF, unity gain 10		%
GBP Gain bandwidth product, f = 100kHz, V_{in} = 10mV, R_L = 2k Ω , C_L = 100pF 2.5 4		MHz
R _i Input resistance 10 ¹²	:	Ω
THD Total harmonic distortion, f= 1kHz, A_v = 20dB, R_L = 2k Ω , C_L =100pF, V_o = 0.01		%
en Equivalent input noise voltage		nV
e_n $R_s = 100\Omega$, f = 1KHz 15		<u>_nV</u> √Hz
Øm Phase margin 45		Degrees
V_{o1}/V_{o2} Channel separation (A _v = 100) 120	1	dB

1. The input bias currents are junction leakage currents which approximately double for every 10°C increase in the junction temperature.

Figure 2. Maximum peak-to-peak output voltage versus frequency





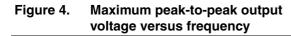


Figure 5. Maximum peak-to-peak output voltage versus free air temp.

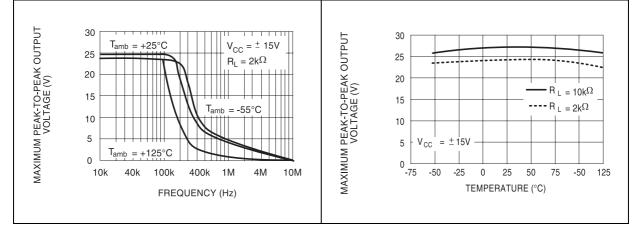
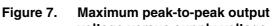


Figure 6. Maximum peak-to-peak output voltage versus load resistance

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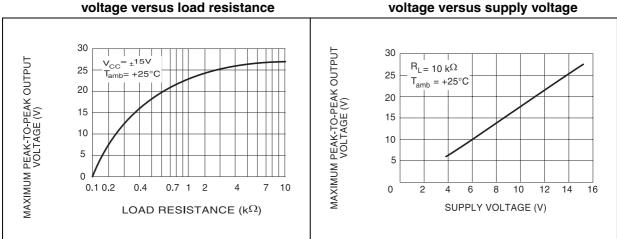
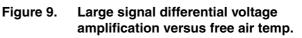
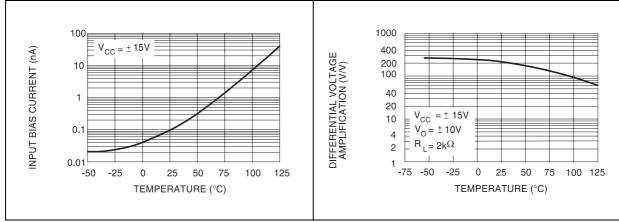
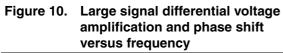
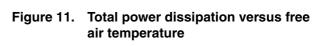


Figure 8. Input bias current versus free air temperature









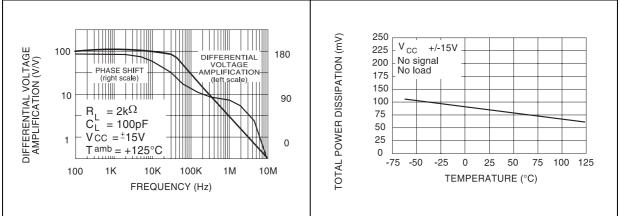


Figure 12.Supply current per amplifier versusFigure 13.Supply current per amplifier versusfree air temperaturesupply voltage

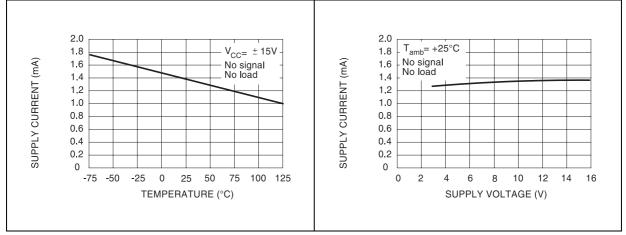
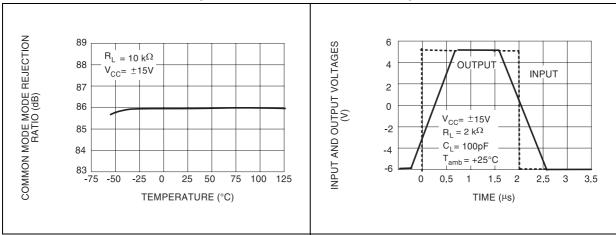
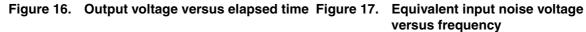


Figure 14. Common mode rejection ratio versus free air temperature







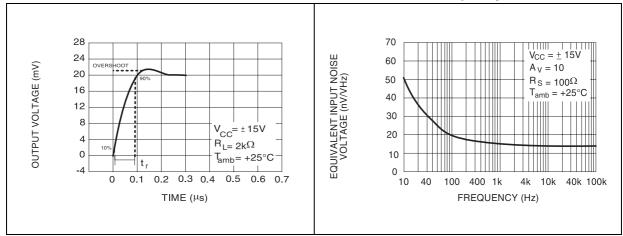
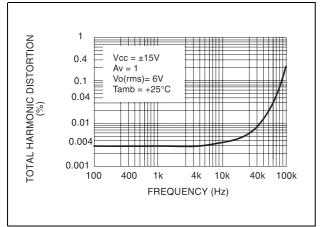
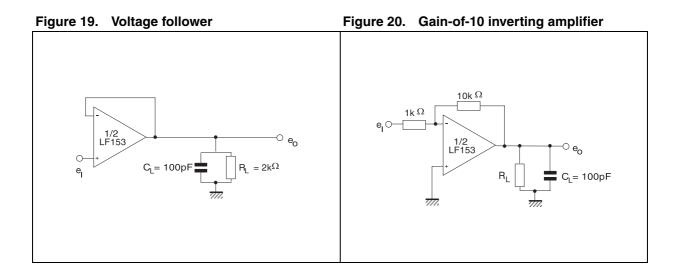


Figure 18. Total harmonic distortion versus frequency

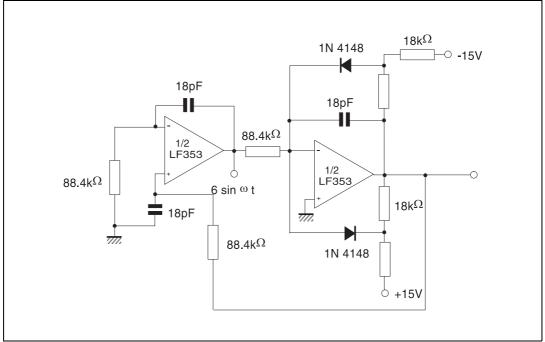


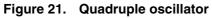
4 Parameter measurement information





5 Typical application





6 Package information

In order to meet environmental requirements, STMicroelectronics offers these devices in ECOPACK[®] packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an STMicroelectronics trademark. ECOPACK specifications are available at: www.st.com.



6.1 DIP8 package information



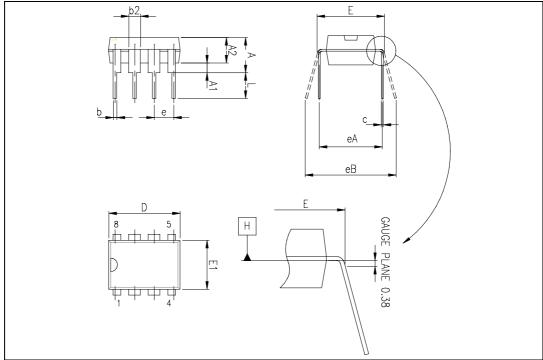


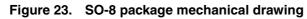
Table 4.DIP8 package mechanical data

	Dimensions					
Ref.	Millimeters			Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.
A			5.33			0.210
A1	0.38			0.015		
A2	2.92	3.30	4.95	0.115	0.130	0.195
b	0.36	0.46	0.56	0.014	0.018	0.022
b2	1.14	1.52	1.78	0.045	0.060	0.070
С	0.20	0.25	0.36	0.008	0.010	0.014
D	9.02	9.27	10.16	0.355	0.365	0.400
E	7.62	7.87	8.26	0.300	0.310	0.325
E1	6.10	6.35	7.11	0.240	0.250	0.280
е		2.54			0.100	
eA		7.62			0.300	
eB			10.92			0.430
L	2.92	3.30	3.81	0.115	0.130	0.150



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6.2 SO-8 package information



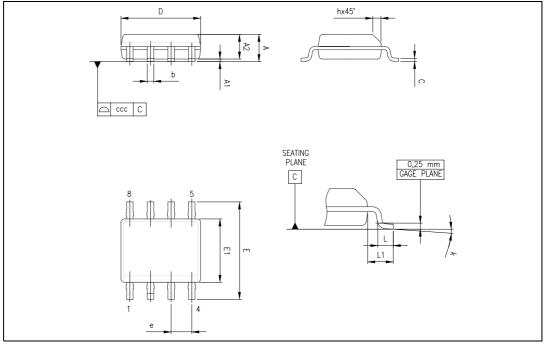


Table 5. SO-8 package mechanical data

	Dimensions					
Ref.		Millimeters			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
А			1.75			0.069
A1	0.10		0.25	0.004		0.010
A2	1.25			0.049		
b	0.28		0.48	0.011		0.019
с	0.17		0.23	0.007		0.010
D	4.80	4.90	5.00	0.189	0.193	0.197
Е	5.80	6.00	6.20	0.228	0.236	0.244
E1	3.80	3.90	4.00	0.150	0.154	0.157
е		1.27			0.050	
h	0.25		0.50	0.010		0.020
L	0.40		1.27	0.016		0.050
L1		1.04			0.040	
k	1°		8°	1°		8°
CCC			0.10			0.004

7 Ordering information

Table 6. Order co	odes
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Order code	Temperature range	Package	Packing	Marking
LF253N		DIP8	Таре	LF253N
LF253D LF253DT	-40°C, +105°C	SO-8	Tape or Tape & reel	253
LF353N		DIP8	Таре	LF353N
LF353D LF353DT	0°C, +70°C	SO-8	Tape or Tape & reel	353

8 Revision history

Table 7. Document revision history

Date	Revision	Changes
01-Mar-2001	1	Initial release.
08-Sep-2008	2	Updated document format. Removed information concerning military temperature range (LF153). Added L1 parameter dimensions in <i>Table 5: SO-8 package</i> <i>mechanical data</i> .

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